NSN 5961-01-354-0374

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View Online at https://aerobasegroup.com/nsn/5961-01-354-0374 **Inclosure Material:** Metal **Overall Length:** 1.550 inches **Overall Height:** Between 0.691 inches and 0.835 inches Overall Width: Between 0.978 inches and 0.995 inches **Mounting Facility Quantity: Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: T0-204 **Electrode Internally-electrically Connected To Case:** Drain **Mounting Method:** Unthreaded hole **Features Provided:** Electrostatic sensitive and hermetically sealed case and quality assurance level tx **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 900.0 drain to gate voltage and 900.0 drain to source voltage and 20.0 gate to source voltage **Current Rating Per Characteristic:** 11.00 amperes source cutoff current of standard range **Power Rating Per Characteristic:** 250.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: